

BZX55 Series



Axial Leaded Glass Zener Diode

Zener Voltage: 2.4 to 75 Volts

DC Power: 0.5 Watts

RoHS Device

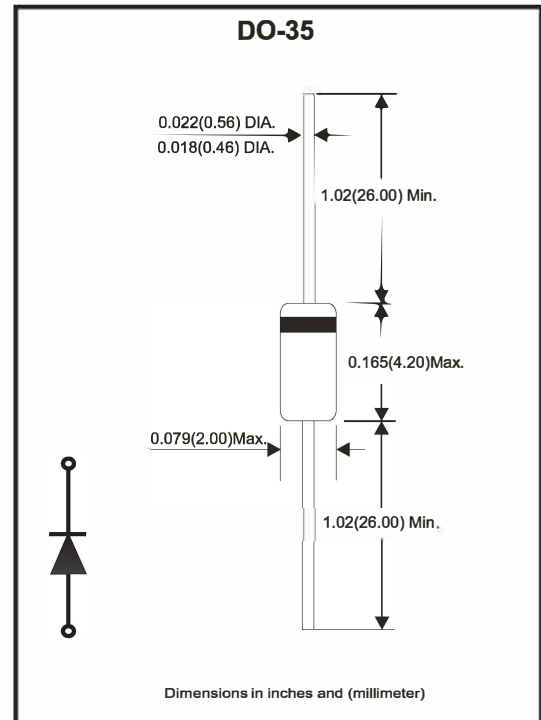


Features

- 500mW power dissipation.
- Stabilizing voltage.

Mechanical data

- Case: Glass, DO-35
- Polarity: Indicated by cathode band



Maximum Ratings (TA=25°C, unless otherwise noted)

Parameter	Conditions	Symbol	Value	Unit
Power dissipation	TL=25°C	Ptot	500	mW
Zener current		Iz	Ptot/Vz	mA
Junction temperature		TJ	175	°C
Storage temperature range		TSTG	-65 to +175	°C

Electrical Characteristics (TA=25°C, unless otherwise noted)

Parameter	Conditions	Symbol	Max	Unit
Thermal resistance (Note 1)	Junction to ambient air L=4mm, TL=25°C	RθJA	300	°C/W
Forward voltage	IF=200mA	VF	1.5	V

Note: Based on dc-measurement at thermal equilibrium; lead length = 9.5 (3/8"); thermal resistance of heat sink =30°C/W

BZX55 Series



Electrical Characteristics (T_A=25°C unless otherwise noted)

BZX55C..

Part Number	Zener voltage range		Dynamic resistance		Test current	Temperature Coefficient		Test current	Reverse leakage current		
	V _Z at I _{ZT}		R _{ZT} at I _{ZT} f = 1 KHz	R _{ZK} at I _{ZK} f = 1 KHz	I _{ZT}	TK _{VZ}		I _{ZK}	I _R at T _{amb} =25°C	I _R at T _{amb} =150°C	at V _R
	V		Ω		mA	%K		mA	μA		V
	Min.	Max.				Min.	Max.				
BZX55C2V4	2.28	2.56	< 85	< 600	5	- 0.09	- 0.06	1	< 50	< 100	1
BZX55C2V7	2.5	2.9	< 85	< 600	5	- 0.09	- 0.06	1	< 10	< 50	1
BZX55C3V0	2.8	3.2	< 85	< 600	5	- 0.08	- 0.05	1	< 4	< 40	1
BZX55C3V3	3.1	3.5	< 85	< 600	5	- 0.08	- 0.05	1	< 2	< 40	1
BZX55C3V6	3.4	3.8	< 85	< 600	5	- 0.08	- 0.05	1	< 2	< 40	1
BZX55C3V9	3.7	4.1	< 85	< 600	5	- 0.08	- 0.05	1	< 2	< 40	1
BZX55C4V3	4	4.6	< 75	< 600	5	- 0.06	- 0.03	1	< 1	< 20	1
BZX55C4V7	4.4	5	< 60	< 600	5	- 0.05	0.02	1	< 0.5	< 10	1
BZX55C5V1	4.8	5.4	< 35	< 550	5	- 0.02	0.02	1	< 0.1	< 2	1
BZX55C5V6	5.2	6	< 25	< 450	5	- 0.05	0.05	1	< 0.1	< 2	1
BZX55C6V2	5.8	6.6	< 10	< 200	5	0.03	0.06	1	< 0.1	< 2	2
BZX55C6V8	6.4	7.2	< 8	< 150	5	0.03	0.07	1	< 0.1	< 2	3
BZX55C7V5	7	7.9	< 7	< 50	5	0.03	0.07	1	< 0.1	< 2	5
BZX55C8V2	7.7	8.7	< 7	< 50	5	0.03	0.08	1	< 0.1	< 2	6.2
BZX55C9V1	8.5	9.6	< 10	< 50	5	0.03	0.09	1	< 0.1	< 2	6.8
BZX55C10	9.4	10.6	< 15	< 70	5	0.03	0.1	1	< 0.1	< 2	7.5
BZX55C11	10.4	11.6	< 20	< 70	5	0.03	0.11	1	< 0.1	< 2	8.2
BZX55C12	11.4	12.7	< 20	< 90	5	0.03	0.11	1	< 0.1	< 2	9.1
BZX55C13	12.4	14.1	< 26	< 110	5	0.03	0.11	1	< 0.1	< 2	10
BZX55C15	13.8	15.6	< 30	< 110	5	0.03	0.11	1	< 0.1	< 2	11
BZX55C16	15.3	17.1	< 40	< 170	5	0.03	0.11	1	< 0.1	< 2	12
BZX55C18	16.8	19.1	< 50	< 170	5	0.03	0.11	1	< 0.1	< 2	13
BZX55C20	18.8	21.2	< 55	< 220	5	0.03	0.11	1	< 0.1	< 2	15
BZX55C22	20.8	23.3	< 55	< 220	5	0.04	0.12	1	< 0.1	< 2	16
BZX55C24	22.8	25.6	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	18
BZX55C27	25.1	28.9	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	20
BZX55C30	28	32	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	22
BZX55C33	31	35	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	24
BZX55C36	34	38	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	27
BZX55C39	37	41	< 90	< 500	2.5	0.04	0.12	0.5	< 0.1	< 5	30
BZX55C43	40	46	< 90	< 600	2.5	0.04	0.12	0.5	< 0.1	< 5	33
BZX55C47	44	50	< 110	< 700	2.5	0.04	0.12	0.5	< 0.1	< 5	36
BZX55C51	48	54	< 125	< 700	2.5	0.04	0.12	0.5	< 0.1	< 10	39
BZX55C56	52	60	< 135	< 1000	2.5	0.04	0.12	0.5	< 0.1	< 10	43
BZX55C62	58	66	< 150	< 1000	2.5	0.04	0.12	0.5	< 0.1	< 10	47
BZX55C68	64	72	< 200	< 1000	2.5	0.04	0.12	0.5	< 0.1	< 10	51
BZX55C75	70	79	< 250	< 1500	2.5	0.04	0.12	0.5	< 0.1	< 10	56

BZX55 Series



Electrical Characteristics (TA=25°C unless otherwise noted)

BZX55B..

Part Number	Zener voltage range		Dynamic resistance		Test current	Temperature Coefficient		Test current	Reverse leakage current		
	V _Z at I _{ZT}		R _{ZT} at I _{ZT} f = 1 KHz	R _{ZK} at I _{ZK} f = 1 KHz	I _{ZT}	TK _{VZ}		I _{ZK}	I _R at T _{amb} =25°C	I _R at T _{amb} =150°C	at V _R
	V		Ω		mA	%K		mA	μA		V
	Min.	Max.				Min.	Max.				
BZX55B2V7	2.64	2.76	< 85	< 600	5	- 0.09	- 0.06	1	< 10	< 50	1
BZX55B3V0	2.94	3.06	< 90	< 600	5	- 0.08	- 0.05	1	< 4	< 40	1
BZX55B3V3	3.24	3.36	< 90	< 600	5	- 0.08	- 0.05	1	< 2	< 40	1
BZX55B3V6	3.52	3.68	< 90	< 600	5	- 0.08	- 0.05	1	< 2	< 40	1
BZX55B3V9	3.82	3.98	< 90	< 600	5	- 0.08	- 0.05	1	< 2	< 40	1
BZX55B4V3	4.22	4.38	< 90	< 600	5	- 0.06	- 0.03	1	< 1	< 20	1
BZX55B4V7	4.6	4.8	< 80	< 600	5	- 0.05	0.02	1	< 0.5	< 10	1
BZX55B5V1	5	5.2	< 60	< 550	5	- 0.02	0.02	1	< 0.1	< 2	1
BZX55B5V6	5.48	5.72	< 40	< 450	5	- 0.05	0.05	1	< 0.1	< 2	1
BZX55B6V2	6.08	6.32	< 10	< 200	5	0.03	0.06	1	< 0.1	< 2	2
BZX55B6V8	6.66	6.94	< 8	< 150	5	0.03	0.07	1	< 0.1	< 2	3
BZX55B7V5	7.35	7.65	< 7	< 50	5	0.03	0.07	1	< 0.1	< 2	5
BZX55B8V2	8.04	8.36	< 7	< 50	5	0.03	0.08	1	< 0.1	< 2	6.2
BZX55B9V1	8.92	9.28	< 10	< 50	5	0.03	0.09	1	< 0.1	< 2	6.8
BZX55B10	9.8	10.2	< 15	< 70	5	0.03	0.1	1	< 0.1	< 2	7.5
BZX55B11	10.78	11.22	< 20	< 70	5	0.03	0.11	1	< 0.1	< 2	8.2
BZX55B12	11.76	12.24	< 20	< 90	5	0.03	0.11	1	< 0.1	< 2	9.1
BZX55B13	12.74	13.26	< 26	< 110	5	0.03	0.11	1	< 0.1	< 2	10
BZX55B15	14.7	15.3	< 30	< 110	5	0.03	0.11	1	< 0.1	< 2	11
BZX55B16	15.7	16.3	< 40	< 170	5	0.03	0.11	1	< 0.1	< 2	12
BZX55B18	17.64	18.36	< 50	< 170	5	0.03	0.11	1	< 0.1	< 2	13
BZX55B20	19.6	20.4	< 55	< 220	5	0.03	0.11	1	< 0.1	< 2	15
BZX55B22	21.55	22.45	< 55	< 220	5	0.04	0.12	1	< 0.1	< 2	16
BZX55B24	23.5	24.5	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	18
BZX55B27	26.4	27.6	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	20
BZX55B30	29.4	30.6	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	22
BZX55B33	32.4	33.6	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	24
BZX55B36	35.3	36.7	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	27
BZX55B39	38.2	39.8	< 90	< 500	2.5	0.04	0.12	0.5	< 0.1	< 5	30
BZX55B43	42.1	43.9	< 90	< 600	2.5	0.04	0.12	0.5	< 0.1	< 5	33
BZX55B47	46.1	47.9	< 110	< 700	2.5	0.04	0.12	0.5	< 0.1	< 5	36
BZX55B51	50	52	< 125	< 700	2.5	0.04	0.12	0.5	< 0.1	< 10	39
BZX55B56	54.9	57.1	< 135	< 1000	2.5	0.04	0.12	0.5	< 0.1	< 10	43
BZX55B62	60.8	63.2	< 150	< 1000	2.5	0.04	0.12	0.5	< 0.1	< 10	47
BZX55B68	66.6	69.4	< 200	< 1000	2.5	0.04	0.12	0.5	< 0.1	< 10	51
BZX55B75	73	76.5	< 250	< 1500	2.5	0.04	0.12	0.5	< 0.1	< 10	56

Rating and Characteristic Curves

FIG1: Total Power Dissipation vs. Ambient Temperature

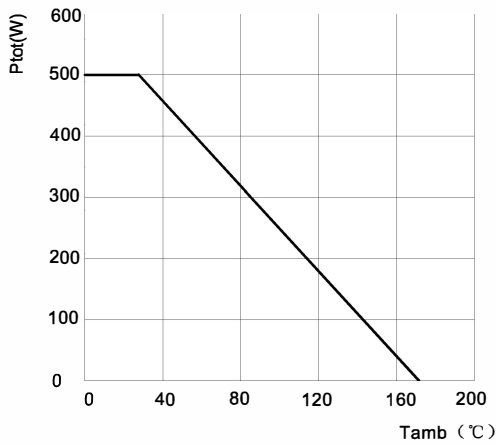


FIG2: Thermal Resistance vs. Lead Length

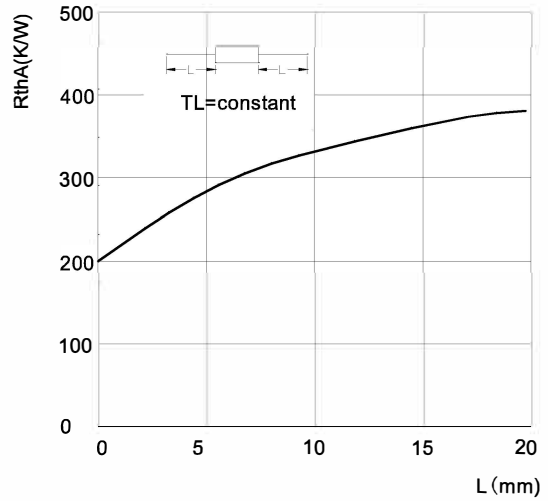


FIG3: Typical Change of Working Voltage under Operating Conditions at T_{amb}=25°C

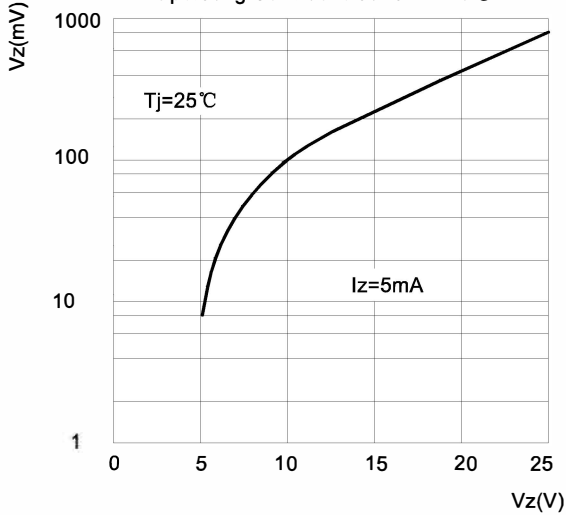


FIG4: Typical Change of Working Voltage vs. Junction Temperature

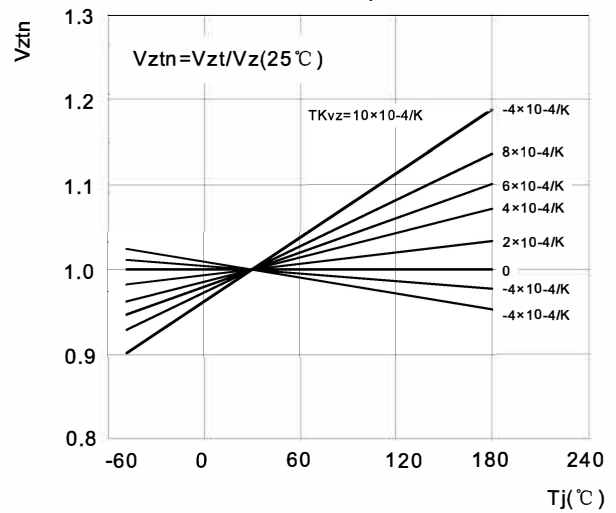


FIG5: Temperature Coefficient of V_z vs. Z-voltage

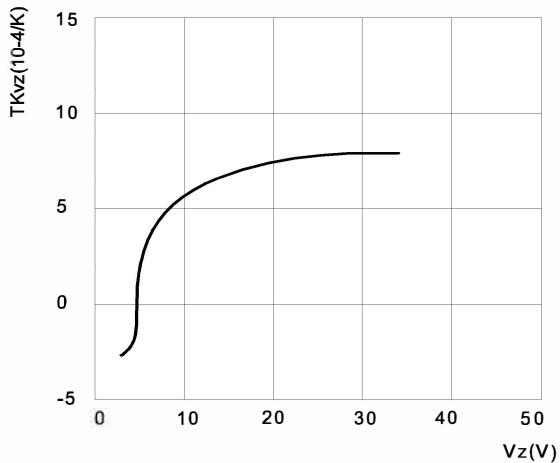
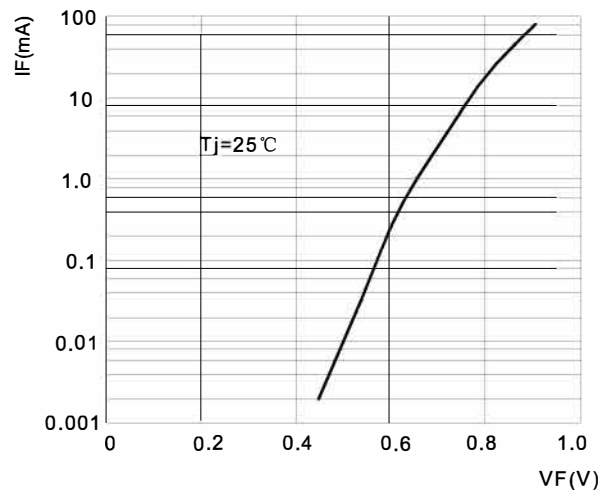
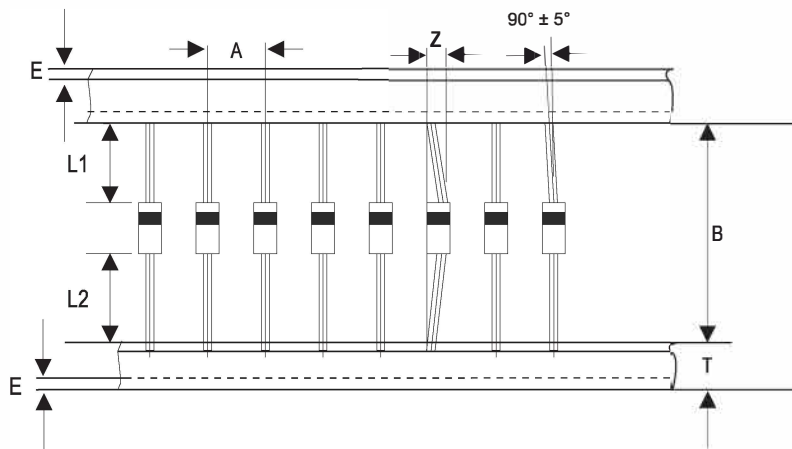


FIG6: Forward Current vs. Forward Voltage



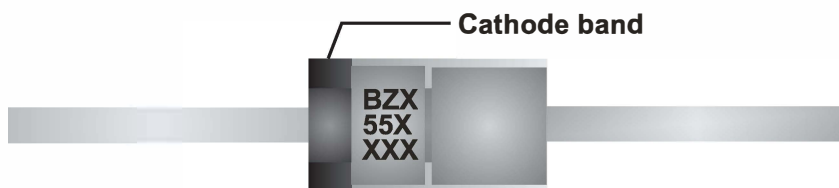
Taping Specification For Axial Lead Diodes



DO-35	SYMBOL	A	B	Z	T	E	L1-L2
	(mm)	5.00 ± 0.5	52.40 ± 1.5	1.60 (max)	6.00 ± 0.4	3.00 (max)	1.00 (max)
	(inch)	0.197 ± 0.020	2.063 ± 0.059	0.063 (max)	0.236 ± 0.016	0.118 (max)	0.039 (max)

Marking Code

Part Number	Marking Code
BZX55 Series	BZX55XXXX



XXXX : Product type marking code (see page.2~3)

Standard Packaging

Case Type	AMMO PACK	
	BOX (pcs)	CARTON (pcs)
DO-35	5,000	100,000

Company reserves the right to improve product design , functions and reliability without notice.